

Silicon Schottky Rectifier in bare die form

Applications

- Switching Power Supply
- Converters
- Free Wheeling Diodes

Electrical Characteristics

Version 1.0 06/04/18

Features

- Ultra Low Reverse Current
- Soft recovery low & high temperature
- Low forward Voltage drop

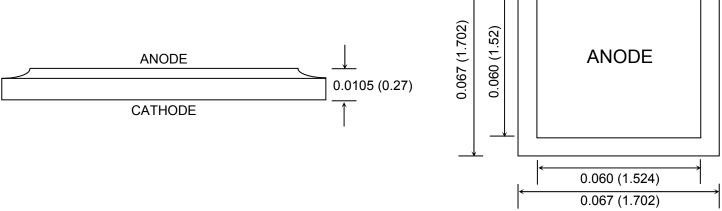
Symbol	Parameter	Conditions	Тур	Max	Unit	
V _R	Reverse Voltage	-	-	60	V	
		V _R = 60V,T _J = 25°C	-	0.15	mA	
I _R	Reverse Current	$^{1}V_{R} = 60V, T_{J} = 125^{\circ}C$	-	10.0	mA	
V _F	Forward Voltage	I _F = 5A @ 25°C	-	0.68	V	
TJ	Junction Temperature	-	-	175	°C	

Note 1: Not production tested at wafer level, tested in package

Mechanical Data

Die Attach Method	Front Metal Composition			Back Metal Composition		
Wire Bondable Top Solderable Back	-	AI (1% Si) 25kÅ	-	Ti	Ni	Ag 30kÅ

Die Drawing - Dimensions in Inches(mm)



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